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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS



Product specification

1998 Jul 29

IC24 Data Handbook



Philips Semiconductors

74ALVCH16823

FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A.
- CMOS low power consumption
- Direct interface with TTL levels
- Current drive ± 24 mA at 3.0 V
- Multibyte™flow-through standard pin-out architecture
- Low inductance multiple V_{CC} and GND pins to minimize noise and ground bounce
- All data inputs have bus hold
- Output drive capability 50Ω transmission lines @ 85°C

DESCRIPTION

The 74ALVCH16823 is a 18-bit edge-triggered flip-flop featuring separate D-type inputs for each flip-flop and 3-state outputs for bus oriented applications. Incorporates bushold data inputs which eliminate the need for external pull-up resistors to hold unused inputs. The74ALVCH16823 consists of two sections of nine edge-triggered flip-flops. A clock (CP) input, an output-enable (OE) input, a Master reset (MR) input and a clock-enable(CE) input are provided for each total 9-bit section.

With the clock-enable (CE) input LOW, the D-type flip-flops will store the state of their individual D-inputs that meet the set-up and hold time requirements on the LOW-to-HIGH CP transition. Taking CE HIGH disables the clock buffer, thus latching the outputs. Taking the Master reset (MR) input LOW causes all the Q outputs to go LOW independently of the clock.

When \overline{OE} is LOW, the contents of the flip-flops are available at the outputs. When the \overline{OE} is HIGH, the outputs go to the high impedance OFF-state. Operation of the OE input does not affect the state of flip-flops.

Active bus hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

SYMBOL	PARAMETER	CONDITIO	NS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay CP to Qn	$V_{CC} = 2.5V, CL = 30pF$ $V_{CC} = 3.3V, CL = 50pF$	V _{CC} = 2.5V, CL = 30pF V _{CC} = 3.3V, CL = 50pF		
F _{max}	Maximum clock frequency	$V_{CC} = 2.5V, CL = 30pF$ $V_{CC} = 3.3V, CL = 50pF$	300 350	MHz	
CI	Input capacitance			5.0	pF
6	Power dissipation consultance per lateh			16	pF
C _{PD}	Power dissipation capacitance per latch	$V_1 = GND$ to V_{CC}^1	Outputs disabled	10	

NOTES:

 C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$ $f_{i} = \text{ input frequency in MHz; } C_{L} = \text{ output load capacity in pF;}$ $f_{o} = \text{ output frequency in MHz; } V_{CC} = \text{ supply voltage in V;}$

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
56-Pin Plastic SSOP Type II	-40°C to +85°C	74ALVCH16823 DL	ACH16823 DL	SOT371-1
56-Pin Plastic TSSOP Type II	-40°C to +85°C	74ALVCH16823 DGG	ACH16823 DGG	SOT364-1

74ALVCH16823

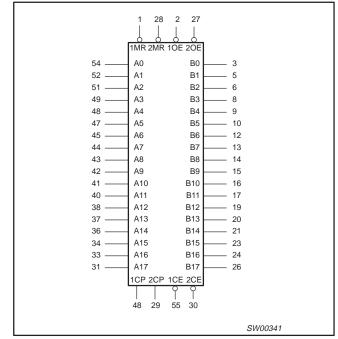
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
2, 27	1 0E , 2 0E	Output enable input (active-Low)
54, 52, 51, 49, 48, 47, 45, 44, 43 42, 41, 40, 38, 37, 36, 34, 33, 31	1D0-1D8 2D0-2D8	Data inputs
3, 5, 6, 8, 9, 10, 12, 13, 14 15, 16, 17, 19, 20, 21, 23, 24, 26	1Q0-1Q8 2Q0-2Q8	Data outputs
56, 29	1CP, 2CP	Clock pulse input (active rising edge)
55, 30	1CE, 2CE	Clock enable input (active-Low)
1, 28	1MR, 2MR	Master reset input (active-Low)
4, 11, 18, 25, 32, 39, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage

PIN CONFIGURATION

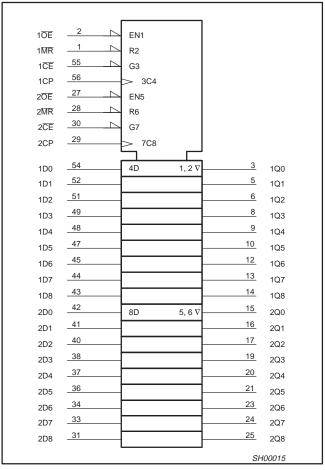
1MR	1	56	1CP
1 0E	2	55	1 CE
1Q0	3	54	1D0
GND	4	53	GND
1Q1	5	52	1D1
1Q2	6	51	1D2
V _{CC}	7	50	V _{CC}
1Q3	8	49	1D3
1Q4	9	48	1D4
1Q5	10	47	1D5
GND	11	46	GND
1Q6	12	45	1D6
1Q7	13	44	1D7
1Q8	14	43	1D8
2Q0	15	42	2D0
2Q1	16	41	2D1
2Q2	17	40	2D2
GND	18	39	GND
2Q3	19	38	2D3
2Q4	20	37	2D4
2Q5	21	36	2D5
V _{CC}	22	35	V _{CC}
2Q6	23	34	2D6
2Q7	24	33	2D7
GND	25	32	GND
2Q8	26	31	2D8
2 0E	27	30	2CE
2MR	28	29	2CP
	۹	Γ-'	
	SH0	0014	
L			

LOGIC SYMBOL

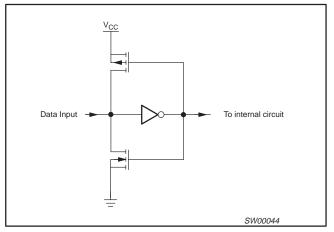


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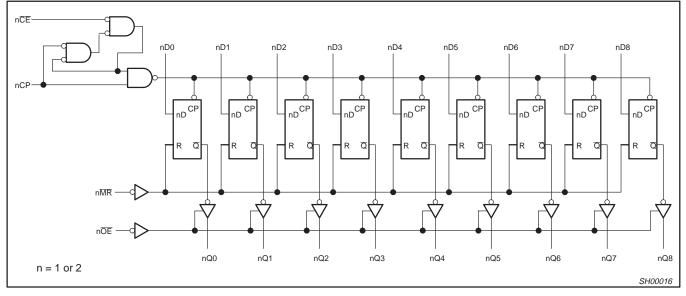
LOGIC SYMBOL (IEEE/IEC)



BUS HOLD CIRCUIT



LOGIC DIAGRAM



74ALVCH16823

FUNCTION TABLE

		INPUTS			OUTPUT	OPERATING MODES
nOE	nMR	nCE	nCP	nDx	nQx	OF ERATING WODES
L	L	Х	Х	Х	L	Clear
L	Н	L	Ŷ	h	Н	Load and read data
L	Н	L	Ŷ	I	L	
L	Н	L	L	Х	Q ₀	Hold
L	Н	Н	Х	Х	Q ₀	
Н	Х	Х	Х	Х	Z	Disable outputs

H = HIGH voltage level

= HIGH voltage level one set-up time prior to the Low-to-High clock transition h

L = LOW voltage level

L = LOW voltage level one set-up time prior to the Low-to-High clock transition

X = Don't care Z = HIGH impe $\uparrow = LOW to Hig$ = HIGH impedance "off" state

= LOW to High clock transition

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT	
STWBUL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7	V
V _{CC}	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	V
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V
N.	DC Input voltage range	for data input pins	0	V _{CC}	V
VI	DC input voltage range	for control pins	0	5.5	V
Vo	DC output voltage range		0	V _{CC}	V
T _{amb}	Operating free-air temperature range		-40	+85	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 2.3 \text{ to } 3.0 \text{V}$ $V_{CC} = 3.0 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
N.		For control pins ¹	-0.5 to +5.5	V
VI	DC input voltage	For data inputs ¹	–0.5 to V _{CC} +0.5	v
I _{ОК}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	±50	mA
V _O	DC output voltage	Note 1	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package –plastic medium-shrink (SSOP) –plastic thin-medium-shrink (TSSOP)	For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW

NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

74ALVCH16823

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

			LIMITS				
SYMBOL	PARAMETER	TEST CONDITIONS	Temp	= -40°C to +8	85°C	UNI	
			MIN	TYP ¹	MAX]	
		$V_{CC} = 1.2V$	V _{CC}				
V _{IH}	HIGH level Input voltage	$V_{CC} = 1.8V$	0.7*V _{CC}	0.9] _	
۲IH	Thomewer input voltage	V _{CC} = 2.3 to 2.7V	1.7	1.2		ľ	
		V _{CC} = 2.7 to 3.6V	2.0	1.5]	
		$V_{CC} = 1.2V$		-	GND		
V _{IL}	LOW level Input voltage	$V_{CC} = 1.8V$		0.9	0.2*V _{CC}	1 .	
۷IL	Low level input voltage	V _{CC} = 2.3 to 2.7V		1.2	0.7		
		V _{CC} = 2.7 to 3.6V		1.5	0.8		
		$V_{CC} = 1.8$ to 3.6V; $V_I = V_{IH}$ or V_{IL} ; $I_O = -100\mu A$	V _{CC} -0.2	V _{CC}	-		
		$V_{CC} = 1.8V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -6mA$	V _{CC} -0.4	V _{CC} -0.10	-	1	
		$V_{CC} = 2.3V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -6mA$	V _{CC} -0.3	V _{CC} -0.08	-	1	
V _{OH}	HIGH level output voltage	$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12mA$	V _{CC} -0.5	V _{CC} _0.17	-	1 v	
		$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -18$ mA	V _{CC} -0.6	V _{CC} -0.26	-	1	
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V _{CC} -0.5	V _{CC} -0.14	-	1	
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -24$ mA	V _{CC} -1.0	V _{CC} -0.28	-	1	
		$V_{CC} = 1.8$ to 3.6V; $V_{I} = V_{IH}$ or V_{IL} ; $I_{O} = 100\mu A$		GND	0.20	\vdash	
	LOW level output voltage	$V_{CC} = 1.8V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 6\text{mA}$		0.09	0.30		
		$V_{CC} = 2.3V; V_I = V_{IH} \text{ or } V_{II}; I_O = 6\text{mA}$		0.07	0.20		
V _{OL}		$V_{CC} = 2.3V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12\text{mA}$		0.15	0.40		
OL		$V_{CC} = 2.3V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 18\text{mA}$		0.23	0.60		
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12\text{mA}$		0.14	0.40		
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL; I_O} = 24\text{mA}$		0.27	0.55		
	Input leakage current per control pin	$V_{CC} = 1.8 \text{ to } 3.6\text{V};$ V ₁ = 5.5V or GND		0.1	5		
łı	Input leakage current per data pin	$V_{CC} = 1.8 \text{ to } 3.6 \text{V};$ $V_{I} = V_{CC} \text{ or GND}$		0.1	5	μ/	
	Input current for common I/O	$V_{CC} = 1.8 \text{ to } 2.7 \text{V};$ $V_{I} = V_{CC} \text{ or GND}$		0.1	10		
I _{IHZ} /I _{ILZ}	pins	$V_{CC} = 3.6V;$ $V_{I} = V_{CC}$ or GND		0.1	15	μ/	
	3-State output OFF-state	V_{CC} = 1.8 to 2.7V; V_I = V_{IH} or V_{IL} ; V_O = V_{CC} or GND		0.1	5		
I _{OZ}	current	V_{CC} = 2.7 to 3.6V; V_I = V_{IH} or V_{IL} ; V_O = V_{CC} or GND		0.1	10	μ/	
ΔI_{CC}	Additional quiescent supply current given per data I/O pin	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$; $I_O = 0$		150	750	μA	
I _{BHL}	Bus hold LOW sustaining	$V_{CC} = 2.3V; V_1 = 0.7V^2$	45	-		μ/	
BHL	current	$V_{CC} = 3.0V; V_1 = 0.8V^2$	75	150		μ	
	Bus hold HIGH sustaining	$V_{CC} = 2.3V; V_{I} = 1.7V^{2}$	-45			μA	
I _{ВНН}	current	$V_{CC} = 3.0V; V_1 = 2.0V^2$	-75	-175		μ/	
lou c	Bus hold LOW overdrive current	$V_{CC} = 2.7 V^2$	300				
IBHLO		$V_{CC} = 3.6 V^2$	450			μA	
louve	Bus hold HIGH overdrive	$V_{CC} = 2.7 V^2$	-300				
внно	current	$V_{CC} = 3.6 V^2$	-450			μA	

NOTES:

1. All typical values are at $T_{amb} = 25^{\circ}C$. 2. Valid for data inputs of bus hold parts.

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AC CHARACTERISTICS FOR V_{CC} = 2.3V TO 2.7V RANGE AND V_{CC} < 2.3V GND = 0V; t_r = t_f \leq 2.0ns; C_L = 30pF

			LIMITS							
SYMBOL	PARAMETER	WAVEFORM	V _{CC} = 2.3 to 2.7V			V _{CC} = 1.8V			V _{CC} = 1.2V	UNIT
			MIN	TYP ^{1, 2}	MAX	MIN	TYP1	MAX	TYP ¹	1
t _{PLH} /t _{PHL}	Propagation delay nCP to nQ _n	1, 5	1.0	2.8	4.9	1.5	4.5	7.5	10.6	ns
t _{PLH} /t _{PHL}	Propagation delay nMR to nQ _n	2, 5	1.0	2.9	5.0	1.5	4.6	7.4	9.9	ns
t _{PZH} /t _{PZL}	3-State output enable time $n\overline{OE}_n$ to nQ_n	4, 5	1.0	2.8	5.3	1.5	4.4	7.7	10.4	ns
t _{PHZ} /t _{PLZ}	3-State output disable time $n\overline{OE}_n$ to nQ_n	4, 5	1.0	2.2	4.1	1.5	3.3	5.5	6.7	ns
t	nCP pulse width	1, 5	3.0	1.6		4.0	2.0			ns
t _W	nMR pulse width, LOW	3, 5	3.0	0.4		4.0	0.8			115
	Set up time nD _n to nCP	3, 5	1.2	0.2		1.5	0.2			ns
tsu	Set up time nCE to nCP	5, 5	1.8	-0.2		2.0	-0.2			115
+	Hold time nD _n to nCP	3, 5	0.8	-0.1		0.6	-0.2			ns
t _h	Hold time nCE to nCP	5, 5	0.3	0.2		0.3	0.2			115
t _{rec}	Recovery time nMR to nCP	2, 5	1.0	0.3		0.8	0.2			ns
F _{max}			150	300		125	250	1		MHz

NOTE:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$. 2. Typical value is measured at $V_{CC} = 2.5V$.

AC CHARACTERISTICS FOR V_{CC} = 3.0V TO 3.6V RANGE AND V_{CC} = 2.7V

GND = 0V; t_{f} = t_{f} \leq 2.5ns; C_{L} = 50pF

			LIMITS						
SYMBOL	PARAMETER	WAVEFORM	V_{CC} = 3.0 ± 0.3V			V _{CC} = 2.7V			UNIT
			MIN	TYP ^{1, 2}	MAX	MIN	TYP ¹	MAX	
t _{PLH} /t _{PHL}	Propagation delay nCP to nQ _n	1, 5	1.0	2.5	3.7	1.0	2.7	4.3	ns
t _{PLH} /t _{PHL}	Propagation delay nMR to nQ _n	2, 5	1.0	2.6	4.0	1.0	3.1	4.6	ns
t _{PZH} /t _{PZL}	3-State output enable time $n\overline{OE}_n$ to nQ_n	4, 5	1.0	2.5	4.3	1.0	3.1	5.2	ns
t _{PHZ} /t _{PLZ}	3-State output disable time $n\overline{OE}_n$ to nQ_n	4, 5	1.0	2.8	3.9	1.0	3.1	4.3	ns
tw	nCP pulse width HIGH or LOW	1, 5	2.5	1.4		3.0	1.6		ns
τψγ	nMR pulse width HIGH or LOW	3, 5	2.5	0.3		3.0	0.6		115
tau	Set up time nD _n to nCP	3, 5	1.2	0.2		1.5	0.4		ns
ts∪	Set up time nCE to nCP	5, 5	1.5	-0.1		1.9	-0.1		115
t .	Hold time nD _n to nCP	3, 5	0.8	0.0		0.6	-0.2		ns
t _h	Hold time nCE to nCP	3, 5	0.5	0.1		0.4	0.1		115
t _{rec}	Recovery time nMR to nCP	2, 5	1.0	0.2		0.8	0.1		ns
F _{max}	Maximum clock pulse frequency	1, 5	200	350		150	300		MHz

NOTES:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$.

2. Typical value is measured at V_{CC} = 3.3V.

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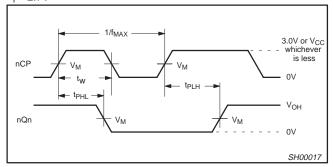
AC WAVEFORMS FOR V_{CC} = 2.3V TO 2.7V AND V_{CC} < 2.3V RANGE

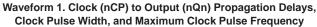
 $\begin{array}{l} V_M = 0.5 \; V_{CC} \\ V_X = V_{OL} + 0.15 V \\ V_Y = V_{OH} - 0.15 V \\ V_{OL} \; \text{and} \; V_{OH} \; \text{are the typical output voltage drop that occur with the output load.} \\ \end{array}$

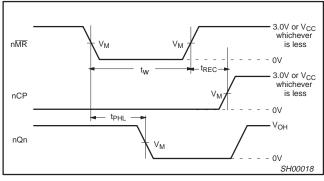
AC WAVEFORMS FOR V_{CC} = 3.0V TO 3.6V AND V_{CC} = 2.7V RANGE

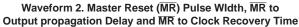
 $V_{M} = 1.5 V$ $V_{X} = V_{OL} + 0.3V$ $V_{Y} = V_{OH} - 0.3V$ V_{OL} and V_{OH} are the f

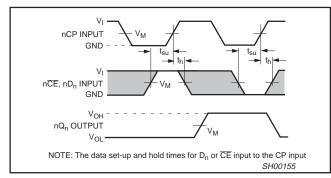
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load. V_{I} = 2.7V



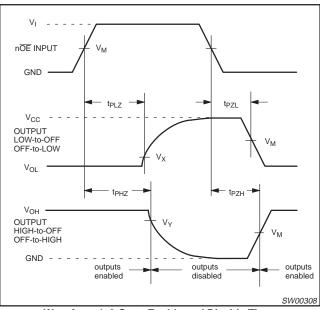






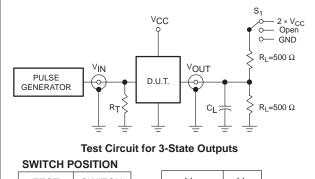


Waveform 3. Data Setup and Hold Times for the D_n or $\overline{\text{CE}}$ input to the CP input



Waveform 4. 3-State Enable and Disable Times

TEST CIRCUIT



TEST	SWITCH	V _{CC}	VIN
t _{PLH} /t _{PHL}	Open	< 2.7V	V _{CC}
t _{PLZ} /t _{PZL}	$2 * V_{CC}$	2.7 – 3.6V	2.7V
t _{PHZ} /t _{PZH}	GND		

DEFINITIONS

R_L = Load resistor

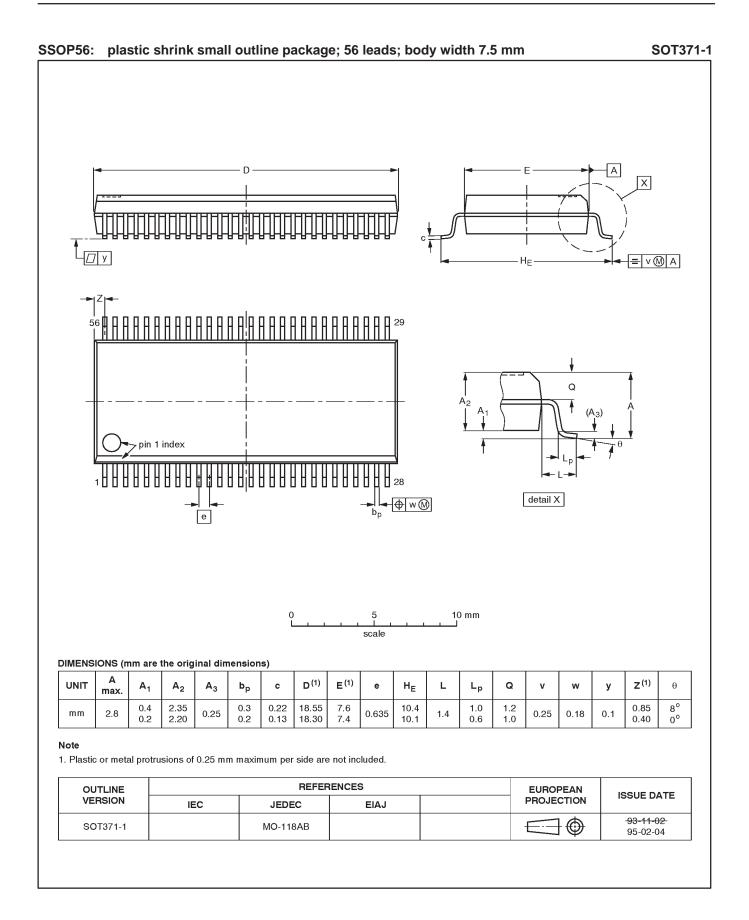
- C_{L}^{-} = Load capacitance includes jig and probe capacitance
- R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

Waveform 5. Load circuitry for switching times

SW00047

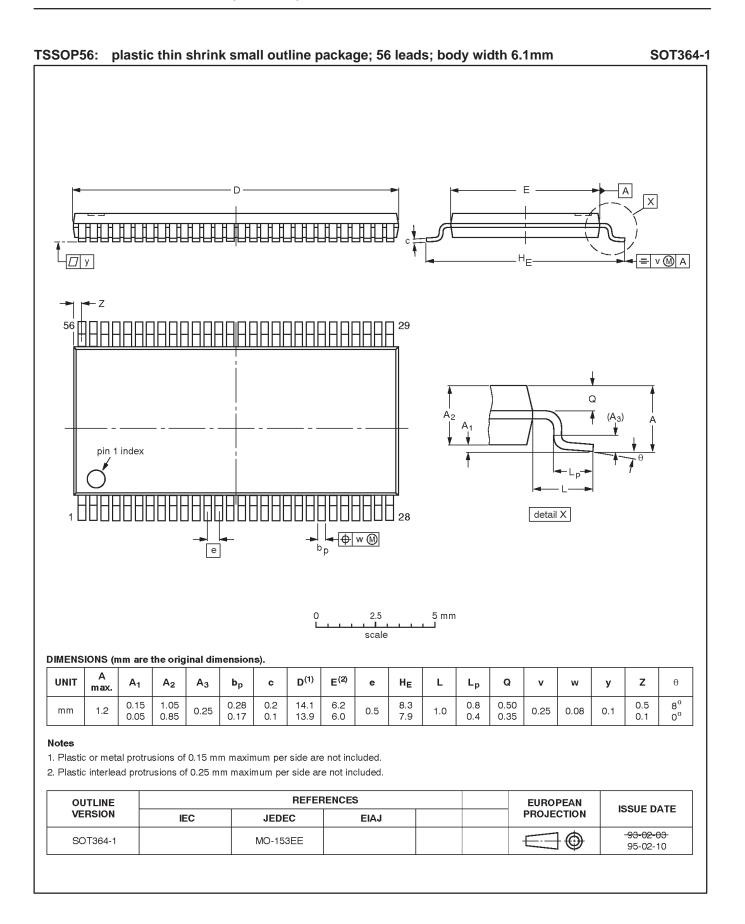
18-bit bus-interface D-type flip-flop with reset and enable (3-State)

74ALVCH16823



18-bit bus-interface D-type flip-flop with reset and enable (3-State)

74ALVCH16823



74ALVCH16823

NOTES

74ALVCH16823

Data sheet status

Data sheet status	Product status	Definition ^[1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

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